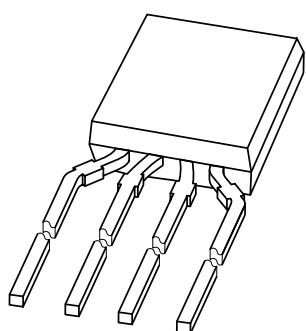


DATA SHEET



KMZ10A1 Magnetic field sensor

Product specification
Supersedes data of 1996 Nov 14
File under Discrete Semiconductors, SC17

1998 Apr 06

Magnetic field sensor

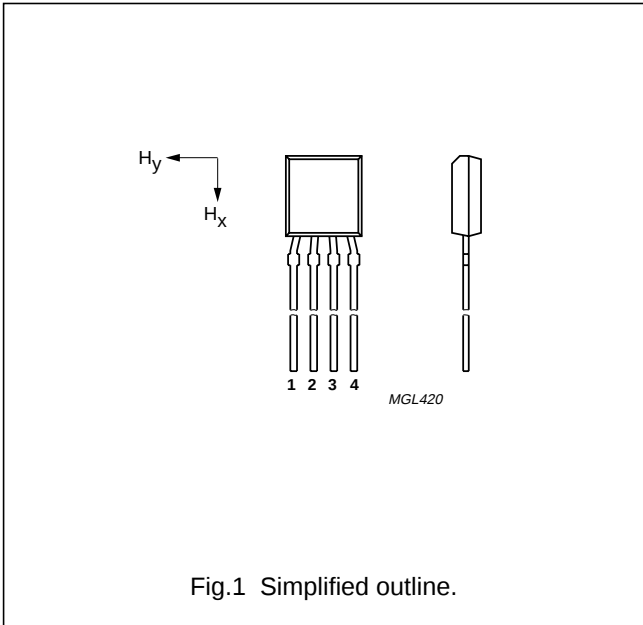
KMZ10A1

DESCRIPTION

The KMZ10A1 is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. Its properties enable this sensor to be used in a wide range of applications such as navigation, current and earth magnetic field measurement etc. The special arrangement of the sensing chip allows the construction of coils for switching the auxiliary field (H_x) along the length axis of the sensor. The sensor can be operated at any frequency between DC and 1 MHz.

PINNING

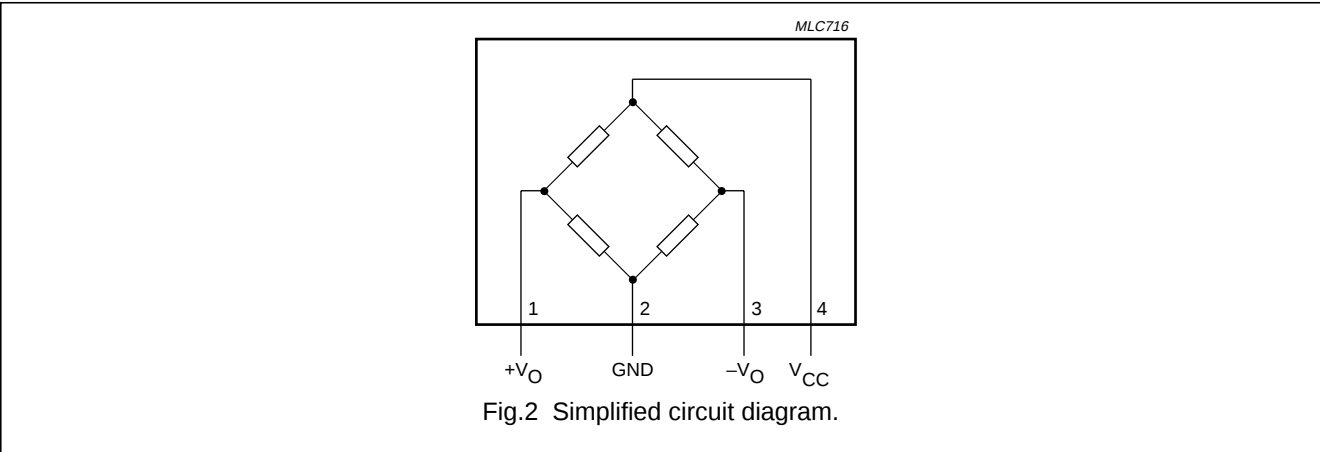
PIN	SYMBOL	DESCRIPTION
1	$+V_O$	output voltage
2	GND	ground
3	$-V_O$	output voltage
4	V_{CC}	supply voltage



QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V_{CC}	DC supply voltage	–	5	–	V
H_y	magnetic field strength	–0.5	–	+0.5	kA/m
H_x	auxiliary field	–	0.5	–	kA/m
S	sensitivity	–	14	–	$\frac{mV/V}{kA/m}$
S_s	sensitivity (with switched H_x)	–	22	–	$\frac{mV/V}{kA/m}$
R_{bridge}	bridge resistance	0.85	–	1.75	k Ω
V_{offset}	offset voltage	–1.5	–	+1.5	mV/V

CIRCUIT DIAGRAM



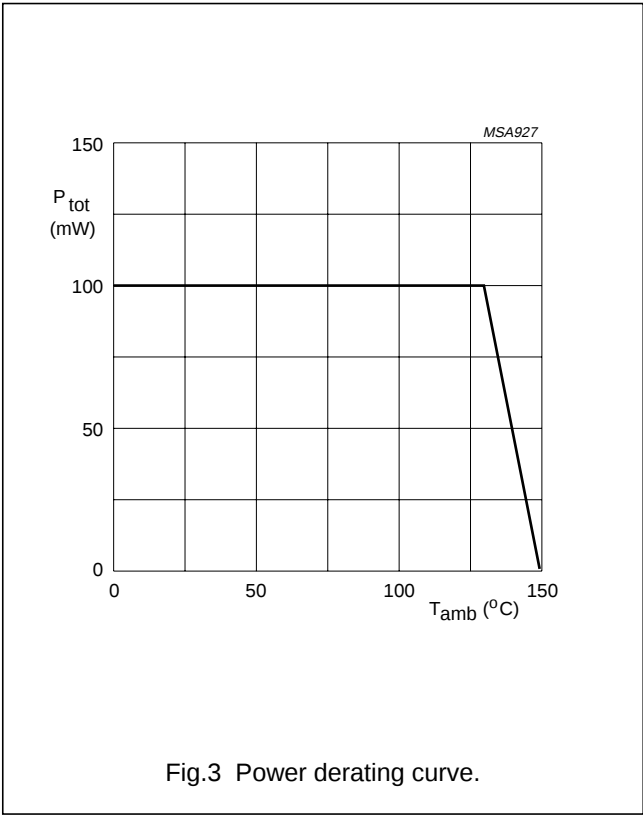
Magnetic field sensor

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	DC supply voltage		–	9	V
P _{tot}	total power dissipation	up to T _{amb} = 132 °C	–	100	mW
T _{stg}	storage temperature		–65	+150	°C
T _{bridge}	bridge operating temperature		–40	+150	°C



Magnetic field sensor

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	180	K/W

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ and $H_x = 0.5\text{ kA/m}$ unless otherwise specified; see notes 1 and 2.

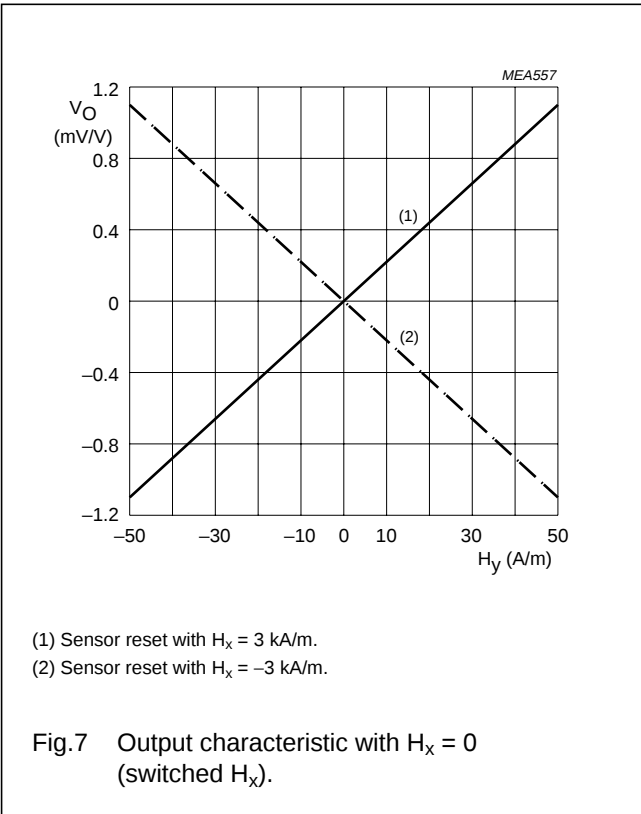
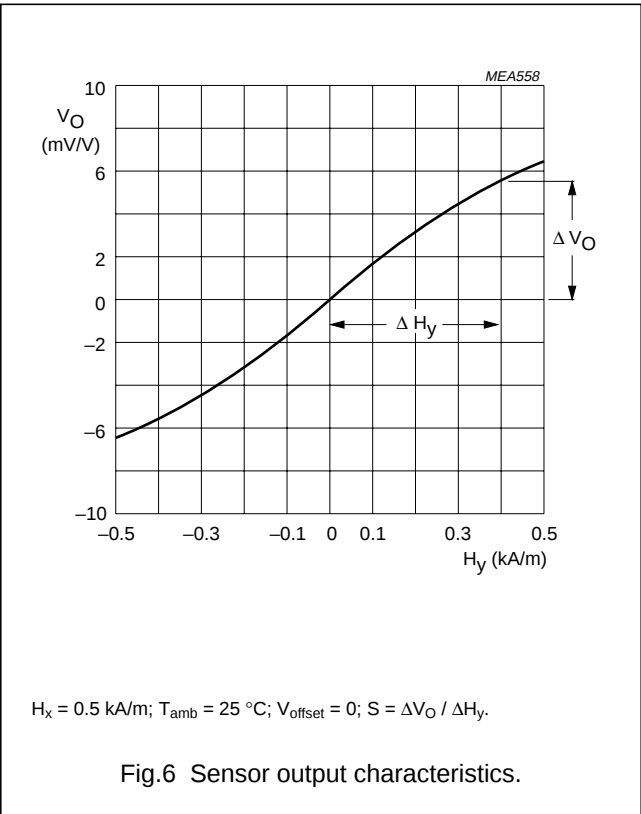
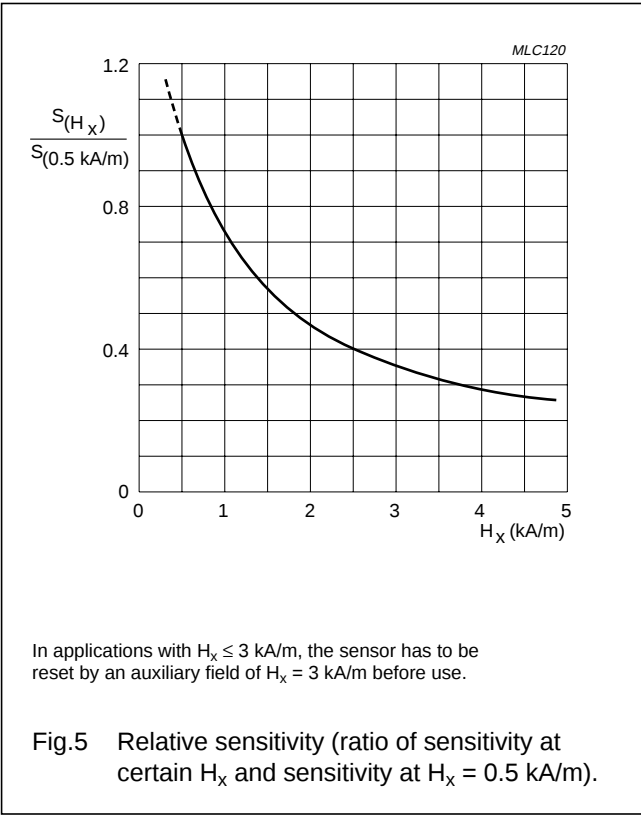
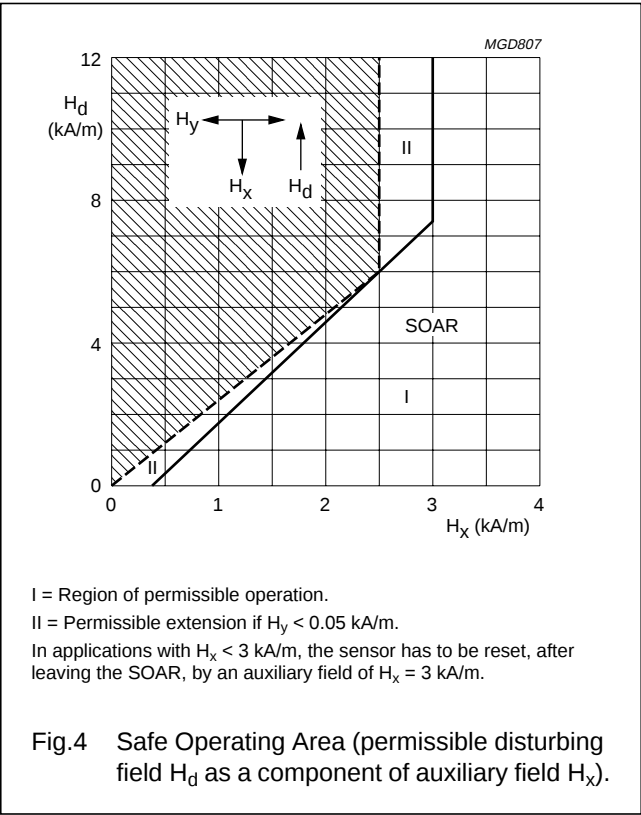
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CC}	DC supply voltage		–	5	–	V
H_y	operating range	note 2	–0.5	–	+0.5	kA/m
S	sensitivity	open circuit; notes 2 and 3	11	–	17	$\frac{mV/V}{kA/m}$
TCV_O	temperature coefficient of output voltage at constant supply voltage	$V_{CC} = 5\text{ V};$ $T_{amb} = -25\text{ to }+125\text{ °C}$	–	–0.4	–	%/K
V_{CV_O}	temperature coefficient of output voltage at constant supply current	$I_B = 3\text{ mA};$ $T_{amb} = -25\text{ to }+125\text{ °C}$	–	–0.15	–	%/K
R_{bridge}	bridge resistance		0.85	–	1.75	k Ω
TCR_{bridge}	temperature coefficient of bridge resistance	$T_j = -25\text{ to }+125\text{ °C}$	–	0.25	–	%/K
V_{offset}	offset voltage		–1.5	–	+1.5	mV/V
TCV_{offset}	offset voltage drift	$T_{bridge} = -25\text{ to }+125\text{ °C}$	–6	–	+6	$\frac{\mu V/V}{K}$
FL	linearity deviation of output voltage	$H_y = 0\text{ to } \pm 0.25\text{ kA/m}^{-1}$	–	–	0.8	%·FS
		$H_y = 0\text{ to } \pm 0.4\text{ kA/m}^{-1}$	–	–	2.5	%·FS
		$H_y = 0\text{ to } \pm 0.5\text{ kA/m}^{-1}$	–	–	4.0	%·FS
FH	hysteresis of output voltage		–	–	0.5	%·FS
f	operating frequency		0	–	1	MHz
Characteristics with $H_x = 0$ (switched H_x, see note 4); $V_{CC} = 5\text{ V}$						
H_y	operating range	note 2	–0.05	–	+0.05	kA/m
S_s	sensitivity	slope between $H_y = 0$ and $H_y = 40\text{ A/m}$	14	–	27	$\frac{mV/V}{kA/m}$

Notes

- Before first operation or after operation outside the SOAR (Fig.4) the sensor has to be reset by application of an auxiliary field $H_x = 3\text{ kA/m}$.
- No disturbing field (H_d) allowed; for stable operation under disturbing conditions see Fig.4 (SOAR) and see Fig.5 for decrease of sensitivity.
- Sensitivity measured as $\Delta V_O / \Delta H_y$ between $H_y = 0$ and $H_y = 0.4\text{ kA/m}$.
- See application information.

Magnetic field sensor

KMZ10A1

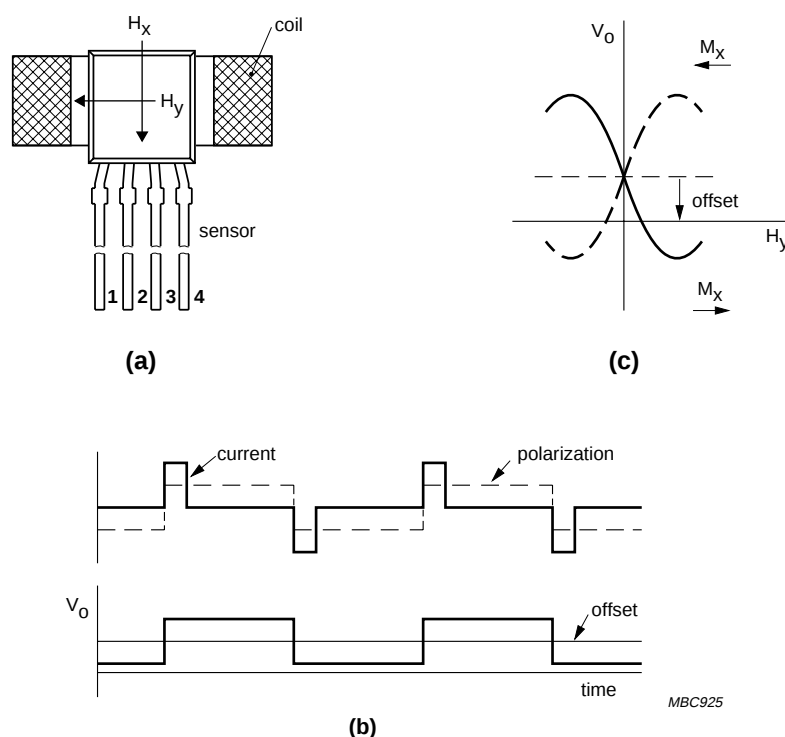


Magnetic field sensor

KMZ10A1

APPLICATION INFORMATION

A problem with measuring weak magnetic fields is that precision is limited by drift in both the sensor and amplifier offset. In these instances, it is possible to take advantage of the 'flipping' characteristics of the KMZ10 series to generate an output that is independent of offset. The sensor, located in a coil connected to a current pulse generator producing magnetic field pulses periodically reversed by alternate positive and negative going current pulses, is continually flipped from its normal to its reversed polarity and back again. The polarity of the offset however, remains unchanged, so the offset itself can be eliminated by passing the output signal through a filter circuit.



- (a) Set-up.
 (b) Pulse diagram.
 (c) Sensor output characteristics.

Fig.8 Measuring weak magnetic fields with the KMZ10A1.

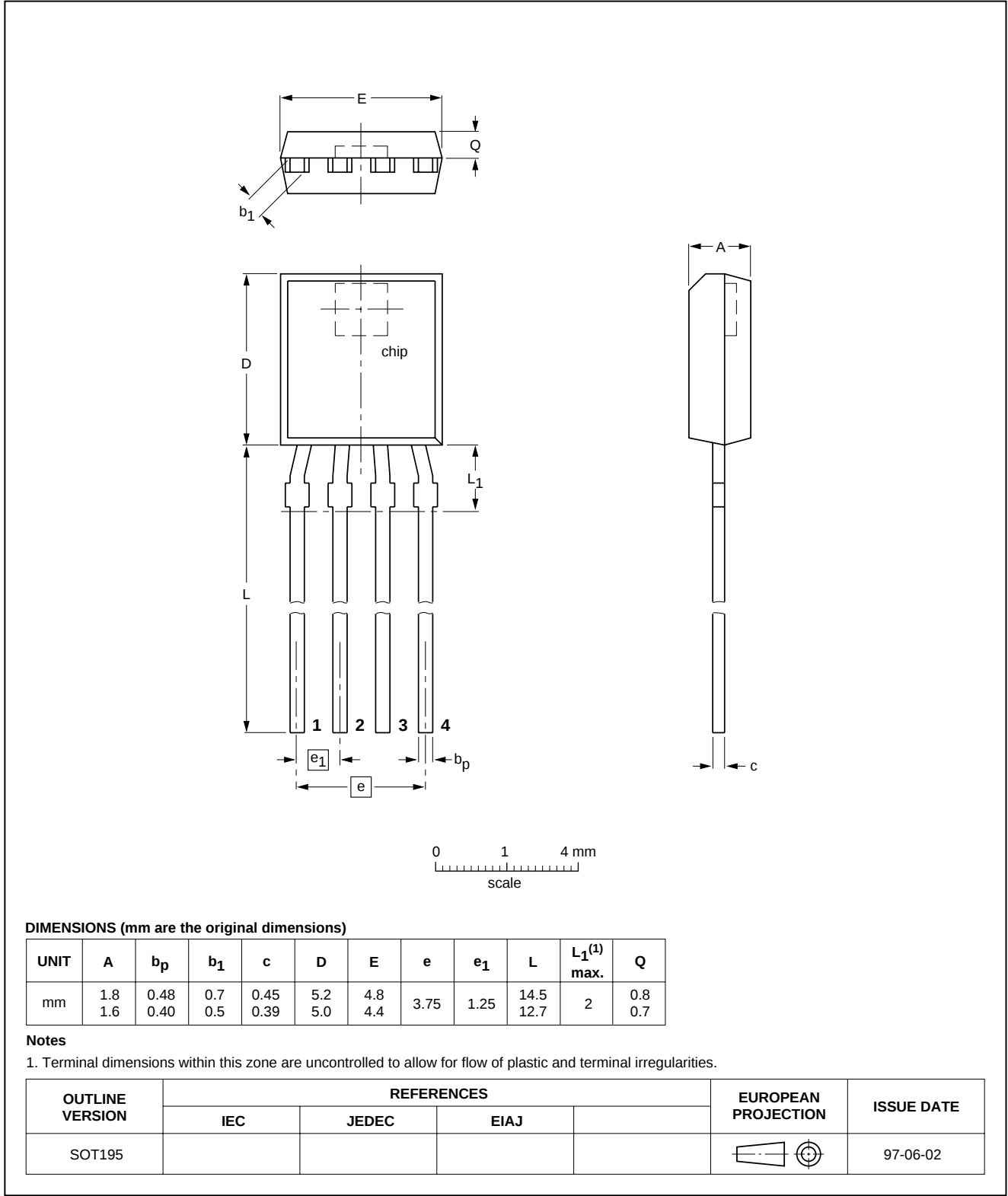
Magnetic field sensor

KMZ10A1

PACKAGE OUTLINE

Plastic single-ended flat package; 4 in-line leads

SOT195



Magnetic field sensor

KMZ10A1

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Magnetic field sensor

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NOTES

Magnetic field sensor

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NOTES

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NOTES

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